

18-Bit Transceiver with 3-State Outputs
Product Features

- PI74ALVCH16863 is designed for low voltage operation
- $V_{CC} = 2.3V$ to $3.6V$
- Hysteresis on all inputs
- Typical V_{OLP} (Output Ground Bounce)
 $< 0.8V$ at $V_{CC} = 3.3V$, $T_A = 25^\circ C$
- Typical V_{OHV} (Output V_{OH} Undershoot)
 $< 2.0V$ at $V_{CC} = 3.3V$, $T_A = 25^\circ C$
- Bus Hold retains last active bus state during 3-State, eliminating the need for external pullup resistors
- Industrial operation at $-40^\circ C$ to $+85^\circ C$
- Packages available:
 - 56-pin 240 mil wide plastic TSSOP (A)
 - 56-pin 300 mil wide plastic SSOP (V)

Product Description

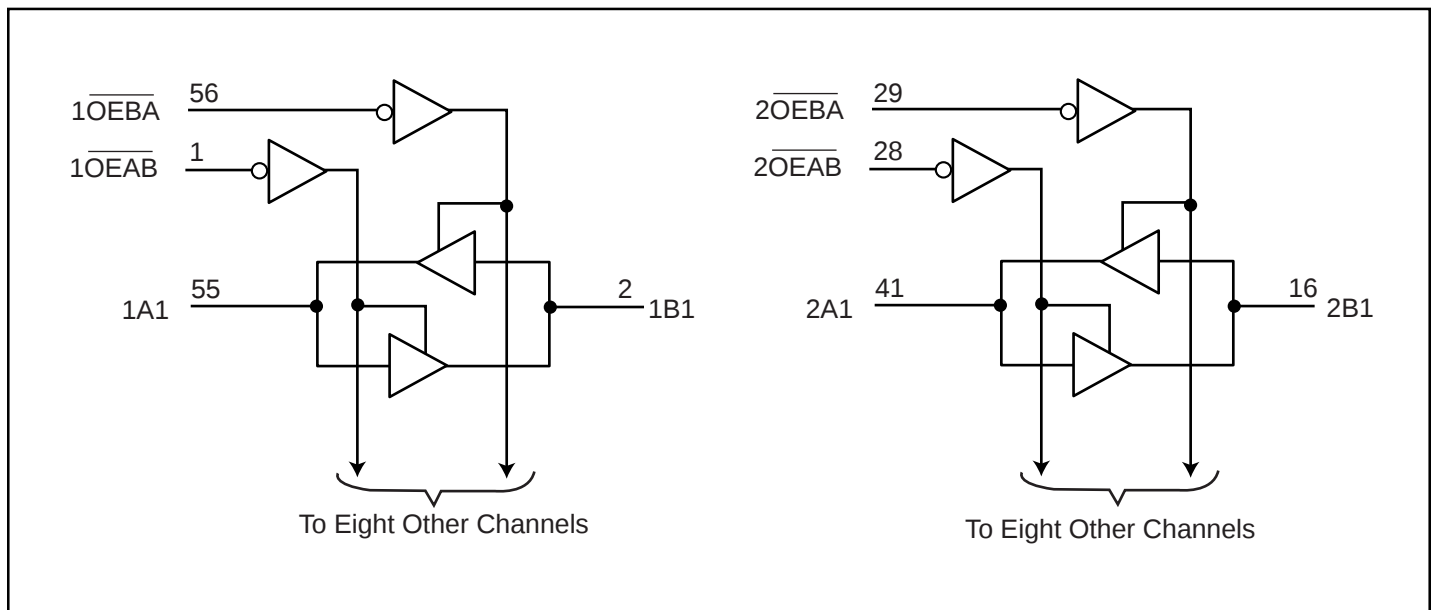
Pericom Semiconductor's PI74ALVCH series of logic circuits are produced in the Company's advanced 0.5 micron CMOS technology, achieving industry leading speed.

The PI74ALVCH16863 is an 18-bit noninverting transceiver designed for synchronous communication between data buses. The control-function implementation minimizes external timing requirements.

The PI74ALVCH16863 can be used as two 9-bit transceivers or one 18-bit transceiver. They allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the output-enable ($\overline{OEAB}$ or $\overline{OEBA}$) inputs.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The PI74ALVCH16863 has "Bus Hold" which retains the data input's last state whenever the data input goes to high-impedance preventing "floating" inputs and eliminating the need for pullup/down resistors.

Logic Block Diagram


Product Pin Description

Pin Name	Description
$\overline{OE}_{xx}$	Output Enable Input (Active LOW)
Ax	Data I/O
Bx	Data I/O
GND	Ground
VCC	Power

Truth Table^{(1)†}

Inputs		Output B
$\overline{OEAB}$	$\overline{OEBA}$	
H	L	B data to A bus
L	H	A data to B bus
H	H	High Impedance

Note:

- H = High Signal Level
L = Low Signal Level
Z = High Impedance
↑ = LOW-to-HIGH Transition

Product Pin Configuration

$\overline{1OEAB}$	1	56	$\overline{1OEBA}$
1B1	2	55	1A1
1B2	3	54	1A2
GND	4	53	GND
1B3	5	52	1A3
1B4	6	51	1A4
VCC	7	50	VCC
1B5	8	49	1A5
1B6	9	48	1A6
1B7	10	47	1A7
GND	11	46	GND
1B8	12	45	1A8
1B9	13	44	1A9
GND	14	43	GND
GND	15	42	GND
2B1	16	41	2A1
2B2	17	40	2A2
GND	18	39	GND
2B3	19	38	2A3
2B4	20	37	2A4
2B5	21	36	2A5
VCC	22	35	VCC
2B6	23	34	2A6
2B7	24	33	2A7
GND	25	32	GND
2B8	26	31	2A8
2B9	27	30	2A9
$\overline{2OEAB}$	28	29	$\overline{2OEBA}$

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	–65°C to +150°C
Ambient Temperature with Power Applied	–40°C to +85°C
Input Voltage Range, V_{IN}	–0.5V to $V_{CC}+0.5V$
Output Voltage Range, V_{OUT}	–0.5V to $V_{CC}+0.5V$
DC Input Voltage	–0.5V to +5.0V
DC Output Current	100mA
Power Dissipation	1.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions⁽¹⁾

Parameters	Description	Test Conditions	Min.	Typ.	Max.	Units
V_{CC}	Supply Voltage		2.3		3.6	V
V_{IH}	Input HIGH Voltage	$V_{CC} = 2.3V$ to $2.7V$	1.7			
		$V_{CC} = 2.7V$ to $3.6V$	2.0			
V_{IL}	Input LOW Voltage	$V_{CC} = 2.3V$ to $2.7V$			0.7	
		$V_{CC} = 2.7V$ to $3.6V$			0.8	
V_{IN}	Input Voltage		0		V_{CC}	
V_{OUT}	Output Voltage		0		V_{CC}	
I_{OH}	High-level Output Current	$V_{CC} = 2.3V$			-12	mA
		$V_{CC} = 2.7V$			-12	
		$V_{CC} = 3.0V$			-24	
I_{OL}	Low-level Output Current	$V_{CC} = 2.3V$			12	
		$V_{CC} = 2.7V$			12	
		$V_{CC} = 3.0V$			24	
T_A	Operating Free-Air Temperature		-40		85	°C
$\Delta t/\Delta v$	Input Transition Rise or Fall		0		10	ns/V

Note:

- Unused control inputs must be held HIGH or LOW to prevent them from floating.

DC Electrical Characteristics (Over the Operating Range, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 3.3\text{V} \pm 10\%$)

Parameters		Test Conditions	$V_{CC}^{(1)}$	Min.	Typ. ⁽²⁾	Max.	Units
V_{OH}		$I_{OH} = -100\ \mu\text{A}$	Min. to Max.	$V_{CC} - 0.2$			V
		$I_{OH} = -6\ \text{mA}$	$V_{IH} = 1.7\text{V}$	2.3V	2.0		
	$I_{OH} = -12\ \text{mA}$	$V_{IH} = 1.7\text{V}$	2.3V	1.7			
		$V_{IH} = 2.0\text{V}$	2.7V	2.2			
		$V_{IH} = 2.0\text{V}$	3.0V	2.4			
		$I_{OH} = -24\ \text{mA}$	$V_{IH} = 2.0\text{V}$	3.0V	2.0		
V_{OL}		$I_{OL} = 100\ \mu\text{A}$	Min. to Max.			0.2	V
		$I_{OL} = 6\ \text{mA}$	$V_{IL} = 0.7\text{V}$	2.3V		0.4	
	$I_{OL} = 12\ \text{mA}$	$V_{IL} = 0.7\text{V}$	2.3V			0.7	
		$V_{IL} = 0.8\text{V}$	2.7V			0.4	
		$I_{OL} = 24\ \text{mA}$	$V_{IL} = 0.8\text{V}$	3.0V		0.55	
I_I		$V_I = V_{CC}$ or GND		3.6V		± 5	μA
I_I (Hold) ⁽³⁾		$V_I = 0.7\text{V}$	2.3V	45			
		$V_I = 1.7\text{V}$		-45			
		$V_I = 0.8\text{V}$	3.0V	75			
		$V_I = 2.0\text{V}$		-75			
		$V_I = 0$ to 3.6V	3.6V			± 500	
$I_{OZ}^{(4)}$		$V_O = V_{CC}$ or GND		3.6V		± 10	
I_{CC}		$V_I = V_{CC}$ or GND	$I_O = 0$	3.6V		40	
ΔI_{CC}		One input at $V_{CC} - 0.6\text{V}$, Other inputs at V_{CC} or GND		3V to 3.6V		750	
C_I	Control Inputs	$V_I = V_{CC}$ or GND	3.3V		3.5		pF
	Data Inputs				6		
C_{IO}	A or B ports	$V_O = V_{CC}$ or GND	3.3V		7.5		pF

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $V_{CC} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient and maximum loading.
3. Bus Hold maximum dynamic current required to switch the input from one state to another.
4. For I/O ports, the I_{OZ} includes the input leakage current.

Switching Characteristics Over Operating Range⁽¹⁾

Parameters	From (Input)	To (Output)	$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 2.7V$		$V_{CC} = 3.3V \pm 0.3V$		Units
			Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	
t_{PD}	A or B	B or A	1.0	4.1		4	1	3.4	ns
t_{EN}	$\overline{OEAB}$ or $OEBA$	A or B	1.0	5.7		5.8	1.0	4.7	
t_{DIS}	$\overline{OEAB}$ or $OEBA$	A or B	1.3	5.5		4.7	1.4	4.2	

Notes:

1. See test circuit and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.

Operating Characteristics, $T_A = 25^\circ C$

Parameter		Test Conditions	V _{CC} = 2.5V ± 0.2V	V _{CC} = 3.3V ± 0.3V	Units
			Typical		
C _{PD} Power Dissipation Capacitance	Outputs Enabled	C _L = 50pF, f = 10 MHz	21	30	pF
	Outputs Disabled		2	3	